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(71) Applicant (for all designated States except US): CANON KABUSHIKI KAISHA [JP/JP]; 3-30-2, Shimomaruko, Ohta-ku, Tokyo, 1468501 (JP).

(72) Inventors; and

(75) Inventors/Applicants (for US only): KUBOTA, Makoto [JP/JP]; c/o CANON KABUSHIKI KAISHA 3-30-2, Shimomaruko, Ohta-ku, Tokyo, 1468501 (JP). MIYAZAKI, Hajime [JP/JP]; c/o CANON KABUSHIKI KAISHA 3-30-2, Shimomaruko, Ohta-ku, Tokyo, 1468501 (JP). NAKAYAMA, Tomonari [JP/JP]; c/o CANON KABUSHIKI KAISHA 3-30-2, Shimomaruko, Ohta-ku, Tokyo, 1468501 (JP).

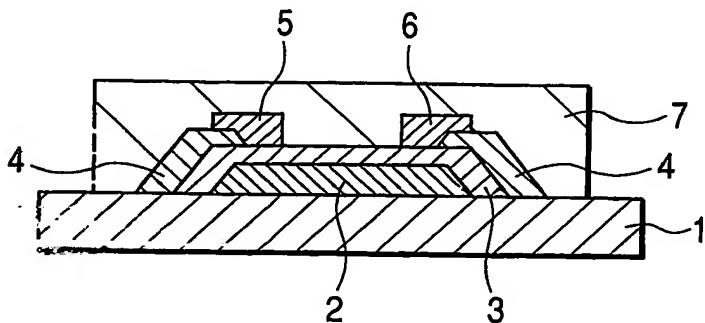
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(54) Title: ORGANIC SEMICONDUCTOR DEVICE



(57) Abstract: An organic semiconductor device that can be driven stably at low gate voltage is provided. The organic semiconductor device of the present invention is characterized by having a silsesquioxane skeleton in an insulating portion.

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